TOSHIBA BIPOLAR LINEAR INTEGRATED CIRCUIT SILICON MONOLITHIC

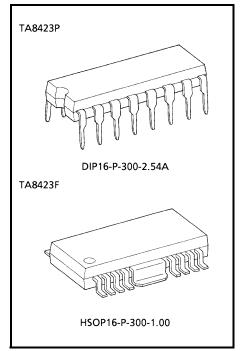
TA8423P,TA8423F

3 PHASE BI-DIRECTIONAL HALL MOTOR DRIVER

The TA8423P, TA8423F are 3 phase Bi–Directional Hall Motor Driver IC designed for VCR (Capstan, head and reel), ADP, Tape Deck, FDD and other Output Driver for 3 phase bipolar Hall motors.

FEATURES

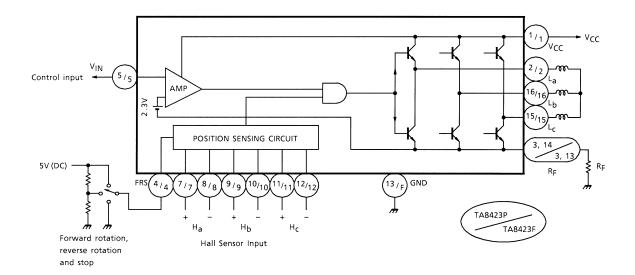
- Few external parts required
- ullet Wide operating supply voltage range
 - $V_{CC \text{ (opr)}} = 7 \sim 17 \text{ V}$
- Forward rotation, reverse rotation and stop are controlled by 1 terminal signal control and easy to interface with CPU.
- High sensitivity of the position sensing circuit. (Hall sensor input) $: V_H = 20 \text{ mV}_{p-p} \text{ (Typ.)}$
- Large output current : Io (MAX.) = 1.2 A
- Protect diodes equipped for all inputs
- Recommend to use TOSHIBA Ga-As Hall sensor "THS100 series"
- Built-in internal reference
- Built-in thermal shut down circuit



Weight

DIP16-P-300-2.54A : 1.11g (Typ.) HSOP16-P-300-1.00 : 0.50g (Typ.)

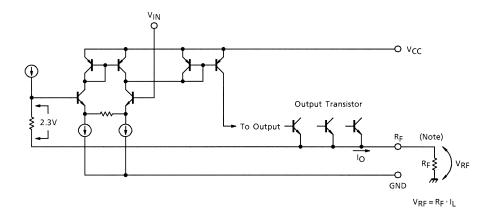
BLOCK DIAGRAM



PIN FUNCTION

PIN No.		0) (140.0)	FUNCTION DESCRIPTION		
Р	F	SYMBOL	FUNCTION DESCRIPTION		
1	1	Vcc	Power supply input terminal.		
2	2	La	a-phase drive output terminal.		
3	3	R _F	Output current detection terminal.		
4	4	FRS	Forward / Reverse control terminal.		
5	5	V _{IN}	Control Amp. positive input terminal.		
6	6	N.C	Non Connection.		
7	7	H _a +	a-phase Hall Amp. positive input terminal.		
8	8	H _a -	a-phase Hall Amp. negative input terminal.		
9	9	H _b +	b-phase Hall Amp. positive input terminal.		
10	10	H _b -	b-phase Hall Amp. negative input terminal.		
11	11	H _c +	c-phase Hall Amp. positive input terminal.		
12	12	H _c -	c-phase Hall Amp. negative input terminal.		
13	FIN	GND	GND terminal.		
14	13	R _F	Output current detection terminal.		
15	15	L _c	c-phase drive output terminal.		
16	16	L _b	b-phase drive output terminal.		

1. Control input circuit

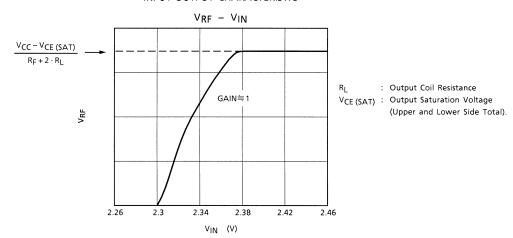


 V_{RF} (= $R_F \cdot I_L$) of feed back voltage is feed backed to negative input of control amp internally. Voltage gain becomes approximately equal to 1 (0dB) by this internal feed back.

Note: 2 terminals (Pin (3), (13) for F version and Pin (3), (14) for P version) are provided for RF terminal to decrease the interference caused by internal common impedance.

Both Pins are required to connect for stable operation.

INPUT-OUTPUT CHARACTERISTIC



 V_{RF} is feed back voltage generated by R_F and output current of I_L , drive current of I_D and internal reference circuit current of I_R .

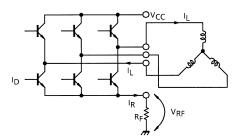
But IO and IR are negligible therefore,

 $I_{\rm R} << I_{\rm L} + I_{\rm D}$

 $V_{RF}\approx R_F\left(I_L+I_O+I_R\right)$

 $I_L \gg I_D, I_R$

 $V_{RF}\approx R_F \cdot I_L$

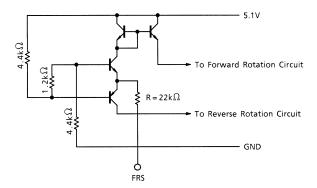


0 Torque state is obtained when less than 2.3 V of control voltage fed into input terminal.

0 Torque state also obtained by select a stop mode by controlling FRS input (Pin (4)).

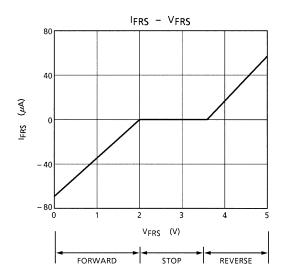
Less supply current is obtained with this condition.

2. FRS CIRCUIT



Forward, Reverse and Stop Modes are selectable by controlling this terminal. Specified voltages are less than 1.3 V (Forward), 2.4 \sim 3.0 V or Open (Stop) and 3.9 V \sim VCC (Reverse). VFRS – IFRS characteristic is shown below.

4



FUNCTION

EDO INIDIJE	POSITIO	N SENSIN	G INPUT	OUTPUT			
FRS INPUT	Ha	H _b	H _c	L _a	L _b	L _c	
	1	0	1	Н	L	М	
	1	0	0	Н	М	L	
L	1	1	0	М	Н	L	
$(V_{(4)} < 1.3 \text{ V})$	0	1	0	L	Н	М	
	0	1	1	L	М	Н	
	0	0	1	М	L	Н	
	1	0	1	L	Н	М	
	1	0	0	L	М	Н	
Н	1	1	0	М	L	Н	
(3.9 V < $V_{(4)}$ < V_{CC})	0	1	0	Н	L	М	
	0	1	1	Н	М	L	
	0	0	1	М	Н	L	
	1	0	1				
	1	0	0	High Impedance (Stop)			
M (2.4 V < V ₍₄₎ < 3.0 V or Open)	1	1	0				
$(2.4 \text{ V} < \text{V}_{(4)} < 3.0 \text{ V or Open})$	0	1	0				
	0	1	1				
	0	0	1				

Note: "1" of the Hall Sensor input means that voltage above +20 mV is applied to the positive side of each Hall Sensor from the negative side and "0" means that voltage above +20 mV is applied to the negative side from the positive side.

In this case, needless to say, DC potential must be within the specified common mode voltage range of Hall Sensor input.

Further, "H", "M" and "L" of output mean $V_{CC} - V_{SAT1} = 1 / 2 V_{CC}$ and V_{SAT2} , respectively.

MAXIMUM RATINGS (Ta = 25°C)

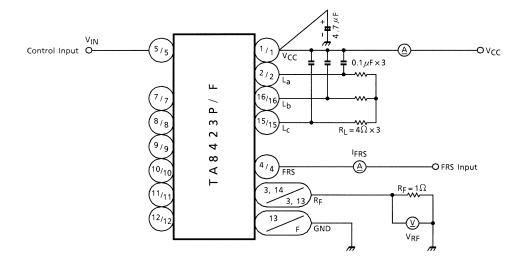
CHARACT	ERISTIC	SYMBOL	RATING	UNIT	
Supply Voltage		Vcc	18	٧	
Output Current		Io	1.2	Α	
Hall Sensor Input Voltage		V _H	400	mV _{p-p}	
	TA8423P		1.2 (Note 1)	W	
Power Dissipation	TA8423F	P _D	0.9 (Note 1)		
			8.3 (Note 2)		
Operating Temperature		Topr	-30~75	°C	
Storage Temperature		T _{stg}	-55~150	°C	

Note 1: No heat sink Note 2: Tc = 25°C

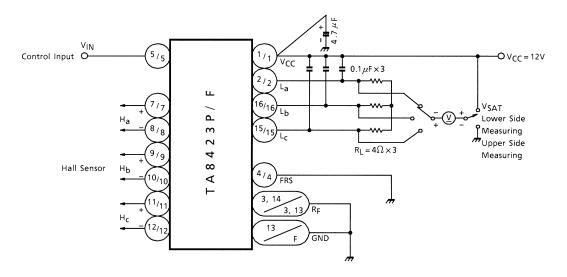
ELECTRICAL CHARACTERISTICS (V_{CC} = 12 V, Ta = 25°C)

CHARACTERISTIC		SYMBOL	TEST CIR-	TEST CONDITION	MIN	TYP.	MAX	UNIT		
		OTMBOL	CUIT	(TA7262P, TA7262P (LB))	101114		WAX	OIVII		
			I _{CC1}		FRS open	4	8	19		
Supply Current		I _{CC2}	1	FRS = 5 V	4.5	9	21	mA		
		I _{CC3}		V _{CC} = 18 V, FRS = GND	5.5	11	22			
	Reference	Voltage	V _{ref}		_	2.2	2.3	2.4	V	
Control Amp.	Voltage Gain		G _V	1	_	_	0	_	dB	
	Input Current		l _{in}		VIN = 3.5 V	_	2.5	10	μA	
	Reference Voltage Ripple Rejection Ratio		R _r		_	-60	_	_	dB	
Cut-off Current		Upper Side	I _{OL} (U)		V _{CC} = 18 V	_	_	50	μA	
		Lower Side	I _{OL (L)}	_	V _{CC} = 18 V	_	_	50	μA	
Saturation Voltage Upper Side Lower Side		V _{SAT1}	2	IL = 1 A	_	1.5	1.9	.9 V		
		Lower Side	V _{SAT2}		IL = 1 A	_	0.8	1.2	\ \ \	
Gain Differe	Gain Difference		ΔG_V	1	_	_	_	±1	%	
Residual O	ual Output Voltage		V _{OR}	1	_	_	0	10	mV	
	Input Sensitivity		V _H	_	_	_	20	_	mV_{p-p}	
Position Sensing Input	Common Mode Voltage Range		CMR _H	3	_	2.0	_	V _{CC} -3	٧	
	Input Offset Voltage		V _{HO}	_	_	_	0	5	mA	
Rotation Control		Forward	V _F		_	-0.3	_	1.3		
(Input Oper		Stop	Vs	1	_	2.4	_	3.0	V	
Voltage)		Reverse	V _R	1	_	3.9	_	V _{CC}		
Thermal Shut-down Circuit Operating Temperature		TSD	_	-	150		_	°C		

TEST CIRCUIT 1

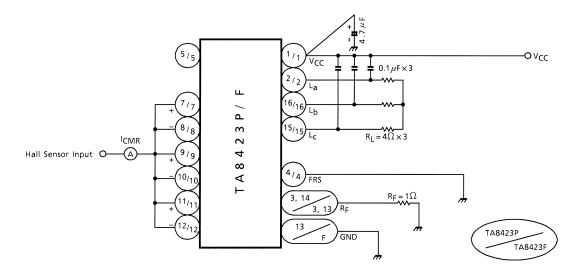


TEST CIRCUIT 2



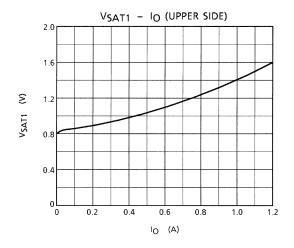
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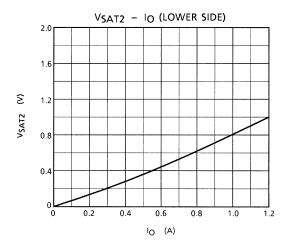
TEST CIRCUIT 3



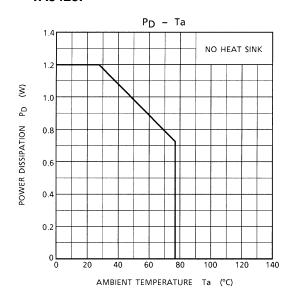
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Output Amplifier Saturation Voltage Characteristics

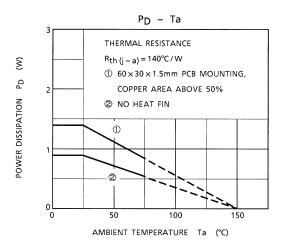




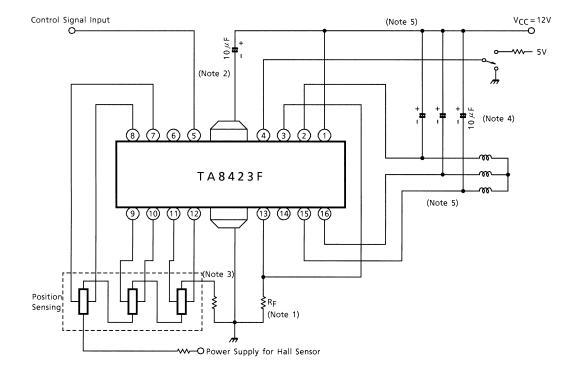
TA8423P



TA8423F



APPLICATION CIRCUIT

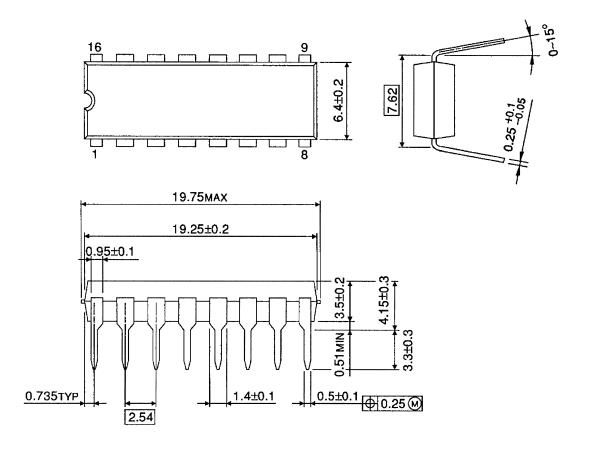


- Note 1: Recommendable value of R_F is 0.3 to 5 Ω . It depends on required initial torque, gain, coil impedance and control voltage of Pin 5.
- Note 2: To connect directly to IC Pin (Fin for F version and (13) Pin for P version) and GND to eliminate the influence of common impedance.

 It is required to increase the value of this capacitance for stable operations in case of poor wiring or patterning of PCB.
- Note 3: Special care should be taken not to have a common impedance with GND line, RF GND line and Hall Sensor GND line.
- Note 4: Please select to optimum value for eliminate a vibration noise and parasitic oscillation. And also to change the connection (for example, each output to V_{CC} or to R_F) for getting better characteristics.
- Note 5: Utmost care is necessary in the design of the output line, V_{CC} and GND line since IC may be destroyed due to short–circuit between outputs, air contamination fault, or fault by improper grounding.

PACKAGE DIMENSIONS

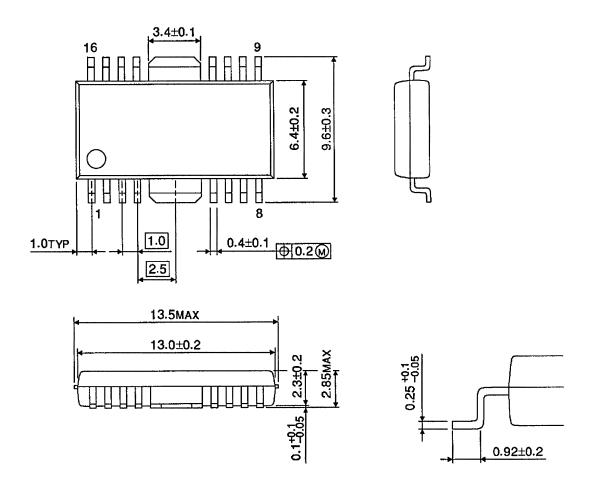
DIP16-P-300-2.54A Unit: mm



Weight: 1.11 g (Typ.)

PACKAGE DIMENSIONS

HSOP16-P-300-1.00 Unit: mm



Weight: 0.50 g (Typ.)

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030619EBA

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